

N-Channel Power MOSFET

## Description

The XR46000 is a silicon N-channel enhanced power MOSFET. With low conduction loss, good switching performance and high avalanche energy, it is suitable for various power supply system, especially for AC step driving application for LED lighting.

The package type is SOT-223, which comply with the RoHS standard.

#### **Key Parameters**

V <sub>DSS</sub>	600V
ID	1.5A
$P_D (T_C = 25^{\circ}C)$	20W
R <sub>DS,ON,typ</sub>	7.0Ω

## **Equivalent Circuit**



Figure 1. Equivalent Cirucit

#### FEATURES

- Fast switching
- ESD improved capability
- Low gate charge (Typ. 7.5nC)
- Low reverse transfer capacitance (Typ. 5.0pF)

#### **APPLICATIONS**

- LED lighting applications
  - Downlight
- High bay
- Specialty
- Architectural

#### **Pin Configuration**



#### **Absolute Maximum Ratings**

Stresses beyond the limits listed below may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

#### $T_C = 25^{\circ}C$ unless otherwise noted.

V <sub>DSS</sub> drain-to-source voltage600	VC
$I_D$ continuous drain current ( $T_C = 25^{\circ}C$ ) 1.8	5A
$I_D$ continuous drain current ( $T_C = 100^{\circ}C$ )0.8	5A
I <sub>DM</sub> pulsed drain current	ôΑ
V <sub>GS</sub> gate-to-source voltage±30	VC
$P_D$ power dissipation ( $T_C = 25^{\circ}C$ )20	W
P <sub>D</sub> derating factor above 25°C0.16W/	°C
T <sub>STORAGE</sub> storage temperature range65°C to 150	°C
E <sub>AS</sub> single pulse avalanche energy80r	nJ
NOTE: Unless otherwise noted, all tests are pulsed tests at the specified temperature,	

Unless otherwise noted, all tests are pulsed tests at the specified temperature therefore:  $T_J = T_C = T_A$ .

#### **Operating Conditions**

$T_J$ operating junction temperature	150°C
T <sub>A</sub> operating ambient temperature	-40°C to 85°C

## **Electrical Characteristics**

 $T_C = 25^{\circ}C$  unless otherwise noted.

Symbol	Parameter	Conditions	Min	Тур	Max	Units	
OFF Characteristic							
BV <sub>DSS</sub>	Drain to source breakdown voltage $V_{GS} = 0V, I_D = 250\mu A$		600			V	
$\Delta BV_{DSS}/\Delta T_{J}$	Breakdown voltage temperature coefficient $I_D = 250\mu$ A, reference 25°C			0.71		V/°C	
	$V_{DS} = 600V, V_{GS} = 0V, T_A = 25^{\circ}C$			25			
I <sub>DSS</sub> Drain to source leakage current		$V_{DS} = 600V, V_{GS} = 0V, T_A = 125^{\circ}C$			250	μA	
I <sub>GSS(F)</sub>	Gate to source forward leakage	V <sub>GS</sub> = 30V			12		
I <sub>GSS(R)</sub>	Gate to source reverse leakage	V <sub>GS</sub> = -28V			-12	- µA	
ON Charact	eristic (pulse width tp $\leq$ 380µs, $\delta \leq$ 2%)		<u>.</u>		<u> </u>	<u> </u>	
R <sub>DS(ON)</sub>	Drain to source on-resistance	V <sub>GS</sub> = 10V, I <sub>D</sub> = 0.75A		7.0	8.0	Ω	
V <sub>GS(TH)</sub>	Gate threshold voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	2.0		4.0	V	
Dynamic Ch	aracteristic	-					
9fs	Forward transconductance	$V_{DS} = 15V, I_D = 0.75A$		1.0		s	
C <sub>iss</sub>	Input capacitance			170			
C <sub>oss</sub>	Output capacitance	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 25V, f = 1MHz		27		pF	
C <sub>rss</sub>	Reverse transfer capacitance			5			
Resistive Sv	vitching Characteristic						
t <sub>d(ON)</sub>	Turn-on delay time			8			
t <sub>r</sub>	Rise time	I <sub>D</sub> = 1.5A, V <sub>DD</sub> = 300V, V <sub>GS</sub> = 10V,		30			
t <sub>d(OFF)</sub>	Turn-off delay time	$R_{G} = 4.7\Omega$		22		- ns	
t <sub>f</sub>	Fall time			55			
Qg	Total gate charge			7.5			
Q <sub>gs</sub>	Gate to source charge	I <sub>D</sub> = 1.5A, V <sub>DD</sub> = 480V, V <sub>GS</sub> = 10V		1.7		nC	
Q <sub>gd</sub>	Gate to drain "Miller" charge			4.0		1	
Source-Drain Diode Characteristics (pulse width tp $\leq$ 380us, $\delta \leq$ 2%)							
I <sub>S</sub>	Continuous source current (body diode)				1.5	•	
I <sub>SM</sub>	Maximun source current (body diode)				6.0	A	
V <sub>SD</sub>	Diode forward voltage	I <sub>S</sub> = 1.5A, V <sub>GS</sub> =0V			1.5	V	
T <sub>rr</sub>	Reverse recovery time	$I_D = 1.5A, T_J = 25^{\circ}C, dI_F/dt = 100A/\mu s,$		530		ns	
Q <sub>rr</sub>	Reverse recovery charge			1100		nC	
I <sub>RRM</sub>	Reverse recovery current			4.4		A	



## **Typical Performance Characteristics**





Figure 3. Typical Drain-to-Source ON Resistance vs. Gate Voltage and Drain Current







# Package Description

Top View







Front View

Side View

3 Pin SOT-223 JEDEC TO-261 Variation AA						
SYMBOLS	DIMENSIONS IN MM (Control Unit)			DIMENSIONS IN INCH (Reference Unit)		
	MIN	NOM	MAX	MIN	NOM	MAX
A	_	—	1.80	_	—	0.071
A1	0.02	—	0.10	0.001	—	0.004
A2	1.50	1.60	1.70	0.060	0.063	0.067
b	0.66	0.76	0.84	0.026	0.030	0.033
b2	2.90	3.00	3.10	0.114	0.118	0.122
с	0.23	0.30	0.35	0.010	0.012	0.014
D	6.30	6.50	6.70	0.248	0.256	0.264
E	6.70	7.00	7.30	0.264	0.276	0.287
E1	3.30	3.50	3.70	0.130	0.138	0.146
е	2.30 BSC			0	).091 B	SC
e1	4.60 BSC			C	).182 B	SC
L	0.75	—	_	0.030	—	—
L2	0.25 BSC			0	.010 BS	SC
θ	0°	—	10°	0°	—	10°
N	3				3	



## Ordering Information<sup>(1)</sup>

Part Number	Operating Temperature Range	Package	Packaging Method	Lead Free <sup>(2)</sup>
XR46000ESETR	$-40^{\circ}C \le T_{J} \le 150^{\circ}C$	SOT-223	Tape and reel	Yes

NOTES:

1. Refer to www.maxlinear.com/XR46000 for most up-to-date Ordering Information.

2. Visit <u>www.maxlinear.com</u> for additional information on Environmental Rating.

#### **Revision History**

Revision	Date	Description
1A	Aug 2016	Initial release
1B	Nov 2019	Updated to MaxLinear logo. Updated Ordering Information.



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